

FOSSEE eSim - Research Migration Project

Project Proposal / Approval Document

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Affiliation / Institution	Rajiv Gandhi University of Knowledge Technologies, Nuzvid
Title of the circuit	Design and Transistor-Level Analysis of a Reconfigurable Low-Power 4-bit Array Multiplier Using Hybrid PTL-CMOS Logic

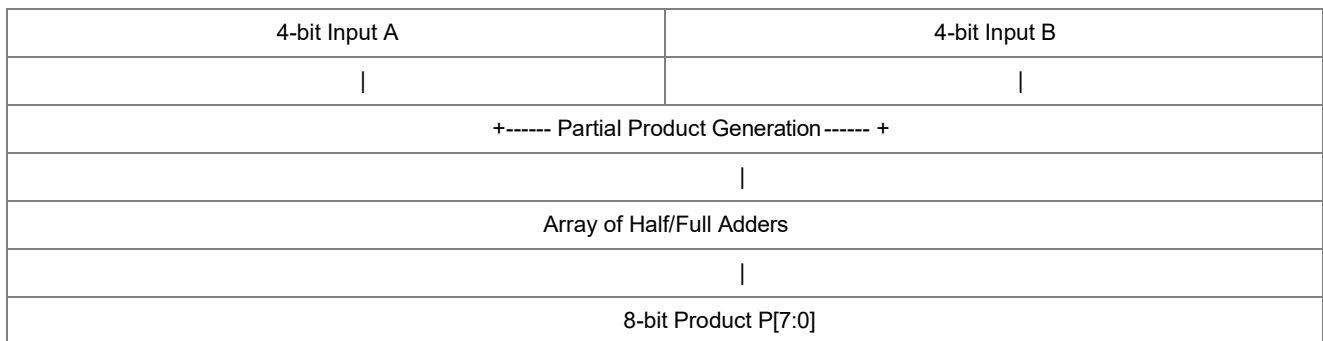
1. Theory / Description

The proposed circuit is a 4-bit binary array multiplier that accepts two 4-bit inputs and produces an 8-bit product. The multiplier first generates partial products using AND operations. These partial products are then added through an array of half-adders and full-adders. To investigate low-power digital VLSI design, selected logic cells are implemented using a Hybrid Pass-Transistor Logic (PTL)-CMOS approach. The design will be evaluated at transistor level in eSim for correct logic operation and performance.

2. Reason to Reproduce / Implement with eSim

eSim provides an open-source environment for schematic capture and circuit simulation. The proposed design is suitable for eSim because its individual CMOS/PTL logic cells, adder stages, partial-product generation and complete multiplier can be verified through simulation. The project also provides educational value by connecting digital multiplication with transistor-level CMOS design and measurable power/delay analysis.

3. Block Diagram



4. Circuit Diagram / Proposed Schematic Structure

The detailed schematic will consist of 16 partial-product generation cells, half-adder and full-adder cells arranged as a 4 x 4 multiplier array, and Hybrid PTL-CMOS implementations for selected logic functions. Each cell will be labelled with its inputs, outputs, supply voltage and transistor connections. The final detailed schematic will be produced during eSim implementation.

A[3:0] x B[3:0]	->	16 partial products	->	Adder array	->	P[7:0]
AND/logic cells		HA/FA stages		Hybrid PTL-CMOS		8-bit output

5. Expected Outcome / Outputs

- Correct 4-bit x 4-bit multiplication for representative input combinations.
- An 8-bit product output waveform that agrees with the expected binary multiplication result.
- Functional verification of the partial-product and adder stages.
- Transistor-level simulation results for the Hybrid PTL-CMOS implementation.
- Measured power consumption and propagation delay, where supported by the simulation setup.
- Power-delay product (PDP) and transistor-count comparison with a conventional CMOS implementation, if both versions are implemented.

6. Expected Results (Input / Output Waveforms)

Example functional checks: A=0011 and B=0010 should produce P=00000110; A=0101 and B=0011 should produce P=00001111. Input signals will be applied as digital voltage waveforms and the output P[7:0] will be observed in the simulator. Power and delay values will be recorded from the final simulation rather than assumed in advance.

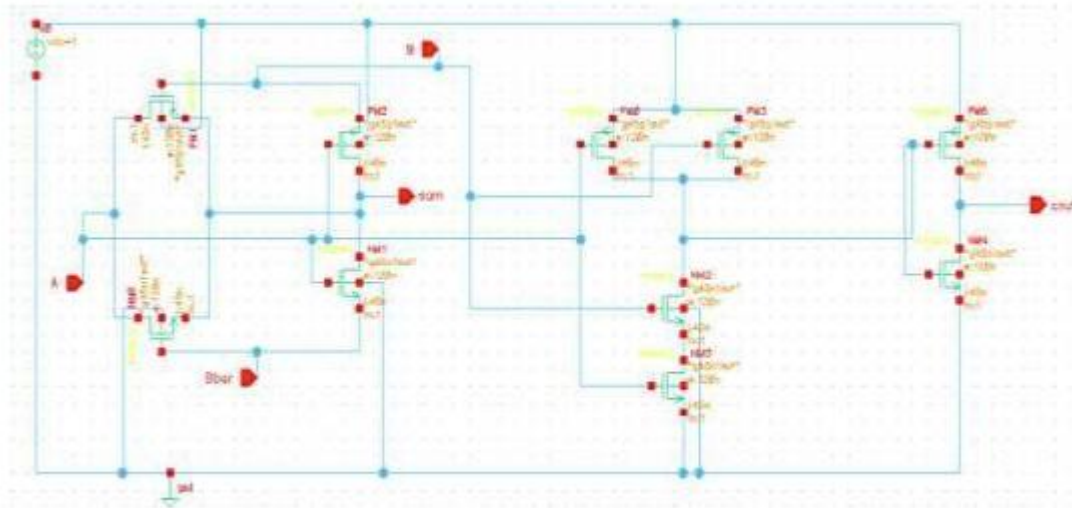


Figure 1 :Half Adder

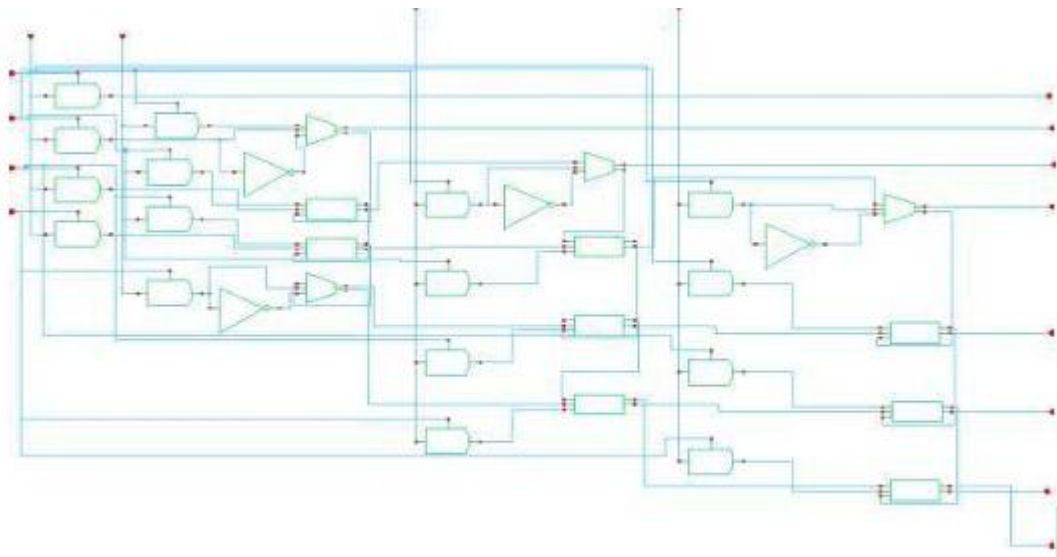


Figure 2 : Schematic of 4-bit Array Multiplier using hybrid PTL and CMOS logic, showing partial product generation and adder network.

7. Research Paper / Journal Reference

The FOSSEE Research Migration Project template requires at least one directly relevant research paper, journal article or patent. **Title:** Low-Power 4-bit Array Multiplier Using Hybrid PTL-CMOS

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8. Source / Reference(s)

FOSSEE eSim Research Migration Project proposal template. The supplied template specifies the required fields for

participant/institution, circuit title, theory/description, reason for eSim, expected outcomes, circuit and block diagrams, expected results, and a mandatory relevant research reference.

Note: This is an approval draft. Final transistor values, waveforms, power, delay and detailed schematic should be filled after eSim implementation